

PSMN038-100HS

N-channel 100 V, 37.6 mOhm, standard level MOSFET in LFPAK56D using TrenchMOS technology

26 September 2022

Product data sheet

1. General description

Dual standard level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology.

2. Features and benefits

- High peak drain current I_{DM}
- Copper clip and flexible Leads
- High operating junction temperature T_i = 175 °C
- Superior reliability
- Low body diode reverse recovery charge Q_r

3. Applications

- · Synchronous rectifier
- Forward and flyback converter
- Industrial drive
- Power management system
- Uninterruptible Power Supply (UPS)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	100	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	21.4	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	53	W
Tj	junction temperature			-55	-	175	°C
Static charac	cteristics FET1 and FET2					'	
DOON	drain-source on-state	V_{GS} = 10 V; I_D = 5 A; T_j = 25 °C; <u>Fig. 11</u>		-	30	37.6	mΩ
	resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 175 °C; Fig. 11; Fig. 12		-	80	104	mΩ
Dynamic cha	aracteristics FET1 and FE	T2					
Q _{GD}	gate-drain charge	I _D = 5 A; V _{DS} = 80 V; V _{GS} = 10 V;		-	9.7	-	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>		-	25.9	-	nC
Avalanche R	uggedness FET1 and FE	Γ2		'	'		'
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 21.4 A; $V_{sup} \le 100$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 4	[1] [2]	-	-	46	mJ



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode FET1 and FET2							
Q _r		$I_S = 5 \text{ A; } dI_S/dt = -100 \text{ A/}\mu\text{s; } V_{GS} = 0 \text{ V; } V_{DS} = 50 \text{ V; } T_j = 25 \text{ °C}$		-	44	-	nC

- [1] Refer to application note AN10273 for further information
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	8 7 6 5	
2	G1	gate1	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	D1 D1 D2 D2
3	S2	source2		
4	G2	gate2		
5	D2	drain2		
6	D2	drain2		
7	D1	drain1	1 2 3 4	S1 G1 S2 G2
8	D1 drain1	drain1	LFPAK56D; Dual LFPAK (SOT1205)	mbk725

6. Ordering information

Table 3. Ordering information

Type number Package					
	Name	Description	Version		
		plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN038-100HS	38RS10H

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	100	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20 \text{ k}\Omega$	-	100	V
V _{GS}	gate-source voltage	DC; T _j ≤ 175 °C	-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	53	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	21.4	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	15	Α

Symbol	Parameter	Conditions		Min	Max	Unit
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	84	Α
T _{stg}	storage temperature			-55	175	°C
T _j	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode FET1 and FET2			'		
Is	source current	T _{mb} = 25 °C		-	21.4	Α
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	84	Α
Avalanche R	Ruggedness FET1 and FET2			'		
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 21.4 A; $V_{sup} \le 100$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; Fig. 4	[1] [2]	-	46	mJ

- [1] Refer to application note AN10273 for further information
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

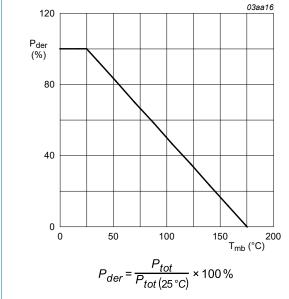


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

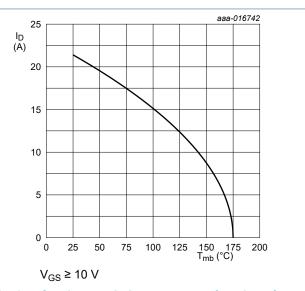
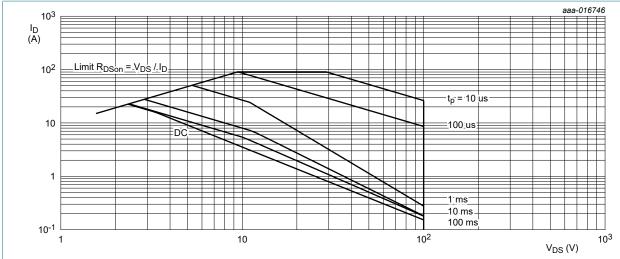
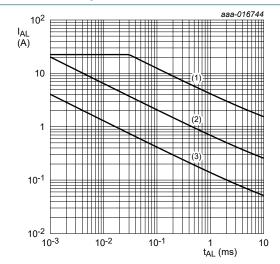


Fig. 2. Continuous drain current as a function of mounting base temperature



T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



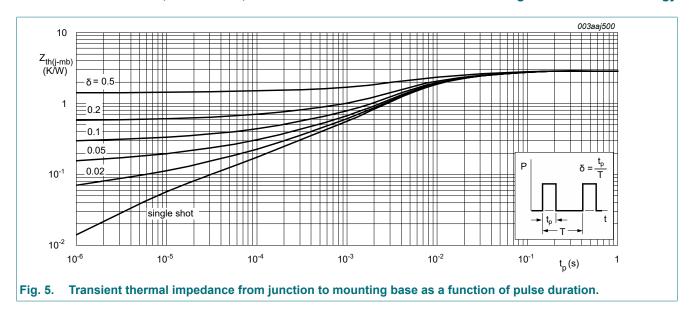
(1) $T_{j \text{ (init)}}$ = 25 °C; (2) $T_{j \text{ (init)}}$ = 150 °C; (3) Repetitive Avalanche

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

9. Thermal characteristics

Table 6. Thermal characteristics

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	-	2.84	K/W	
$R_{th(j-a)}$		Minimum footprint; mounted on a printed circuit board		-	95	-	K/W	



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics FET1 and FET2					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	90	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	100	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}; Fig. 9; Fig. 10$	2.4	3	4	V
		$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 175 \text{ °C};$ Fig. 10	1	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}; Fig. 10$	-	-	4.5	V
I _{DSS}	drain leakage current	V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C	-	0.02	1	μA
		V _{DS} = 100 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μΑ
I _{GSS} gate leakage current	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 25 °C; <u>Fig. 11</u>	-	30	37.6	mΩ
		V _{GS} = 10 V; I _D = 5 A; T _j = 175 °C; Fig. 11; Fig. 12	-	80	104	mΩ
Dynamic ch	naracteristics FET1 and FE	:T2		'		
Q _{G(tot)}	total gate charge	I _D = 5 A; V _{DS} = 80 V; V _{GS} = 10 V;	-	25.9	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u>	-	4.3	-	nC
Q _{GD}	gate-drain charge		-	9.7	-	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;	-	1150	1533	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	-	122	147	pF
C _{rss}	reverse transfer capacitance		-	84	115	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 80 \text{ V}; R_L = 16 \Omega; V_{GS} = 10 \text{ V};$	-	6.2	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	11.2	-	ns
t _{d(off)}	turn-off delay time		-	20.3	-	ns
t _f	fall time		-	13.9	-	ns

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode FET1 and FET2							
V _{SD}	source-drain voltage	$I_S = 5 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}; Fig. 16$		-	0.78	1.2	V
t _{rr}		$I_S = 5 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	32.9	-	ns
Q _r	recovered charge	$V_{DS} = 50 \text{ V}; T_j = 25 \text{ °C}$		-	44	-	nC

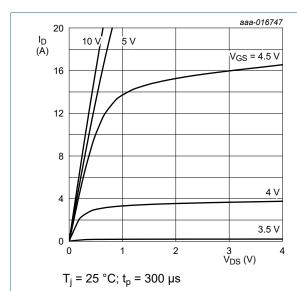


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

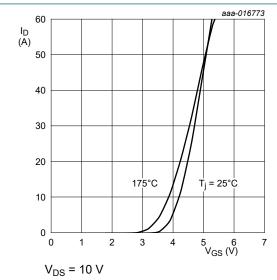


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

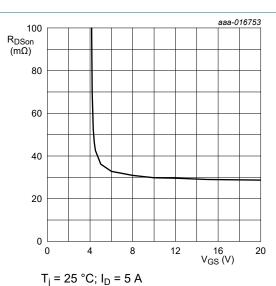
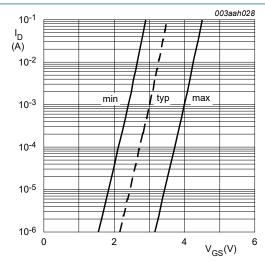


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values



 $T_i = 25 \, ^{\circ}C; \, V_{DS} = 5 \, V$

Fig. 9. Sub-threshold drain current as a function of gate-source voltage

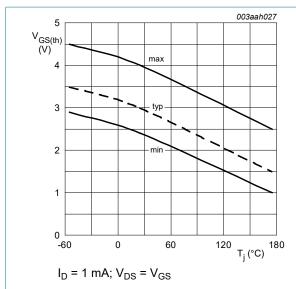


Fig. 10. Gate-source threshold voltage as a function of junction temperature

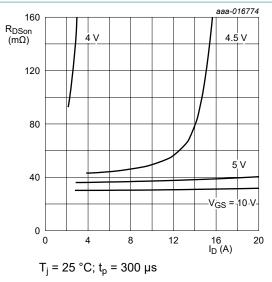


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

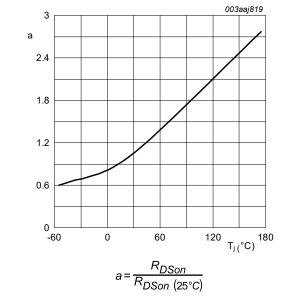


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

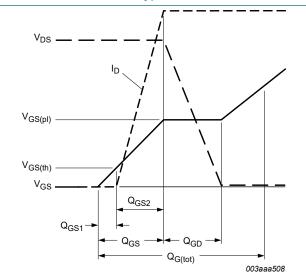


Fig. 13. Gate charge waveform definitions

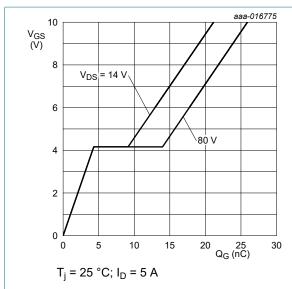


Fig. 14. Gate-source voltage as a function of gate charge; typical values

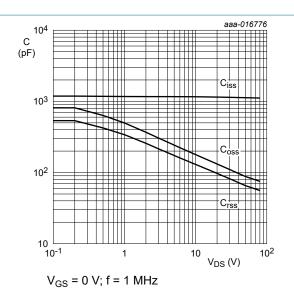


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

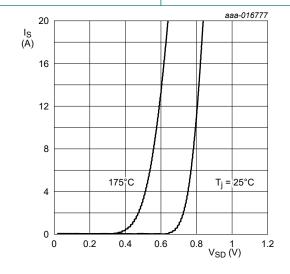
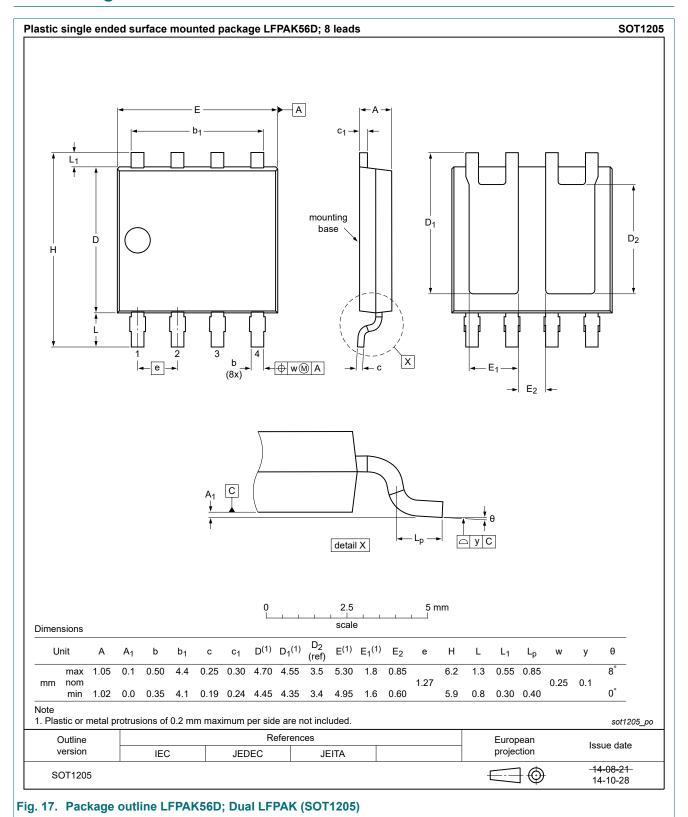


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

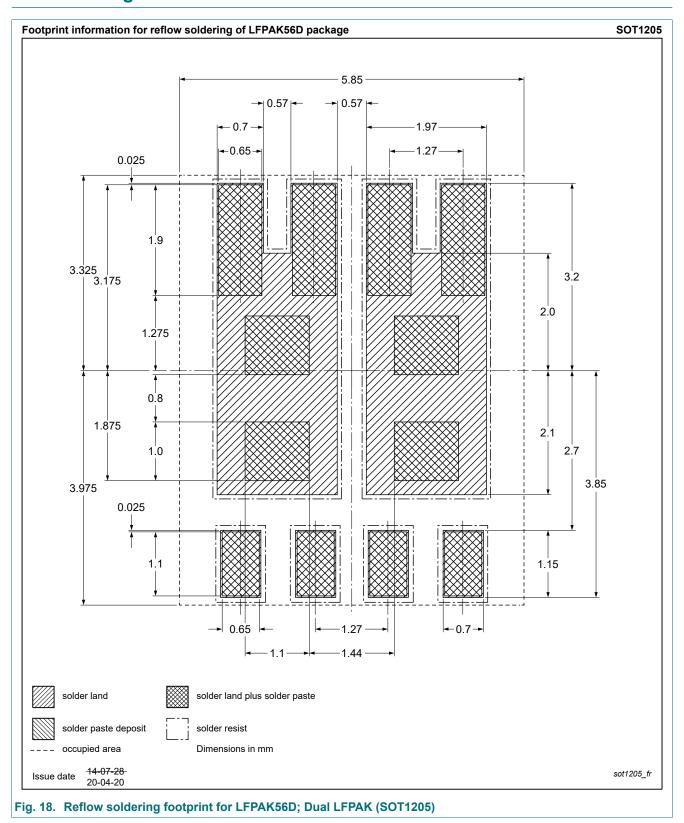
Product data sheet

 $V_{GS} = 0 V$

11. Package outline



12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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